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View Online at https://aerobasegroup.com/nsn/5961-01-115-6673

Inclosure Material: Glass and metal **Overall Length:** Between 0.293 inches and 0.357 inches **Terminal Length:** Between 1.000 inches and 1.625 inches **Overall Diameter:** Between 0.215 inches and 0.235 inches **Function For Which Designed:** Transient suppressor **End Application:** Aux power sys 76301 fscm Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-13 Electrode Internally-electrically Connected To Case: Cathode **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 53.6 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector major Maximum Operating Tempurature Per Measurement Point: 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/500 government specification Shelf Life: N/a Unit Of Measure: **Demilitarization:** No

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Fiig: A110a0

Mil-std (military Standard):

Mil-mil-prf-19500 spec.